

Basics II: electronic convergence and BZ sampling

Doris Vogtenhuber

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University of Vienna, Faculty of Physics, AG-CMP



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Outline

- 1 Electronic Convergence
 - Introduction
 - the SCF-scheme
 - Basic Algorithms used in VASP
- 2 Charge Density Mixing
- 3 Sampling the Brillouin Zone
 - Basics
 - BZ Sampling
 - Files and Parameters, Problem Handling

Determination of the Electronic Groundstate

Overview

- eigenvalue problem to be solved
- general strategies to solve the KS-equations
- algorithms used in VASP
- choice of the appropriate input parameters
- strategies if convergence fails, error handling

the Kohn-Sham Groundstate

the Free Energy Functional

- electronic contribution of the Kohn-Sham free energy F_{KS} at finite T :

$$F_{KS}[\phi, f, \vec{R}] = \sum_n f_n \langle \phi_n | \hat{T} | \phi_n \rangle - \sum_n \sigma S(f_n) \\ + E_H[\rho] + E_{xc}[\phi, f] + \int V_{\text{ion}}(\vec{r}) \rho(\vec{r}) d^3\vec{r}$$

- with contributions of the **kinetic energy**,
- **entropy of non-interacting e^-** ,
- **Hartree term**,
- **exchange-correlation energy** and the
- **ionic potential**

Electronic Convergence

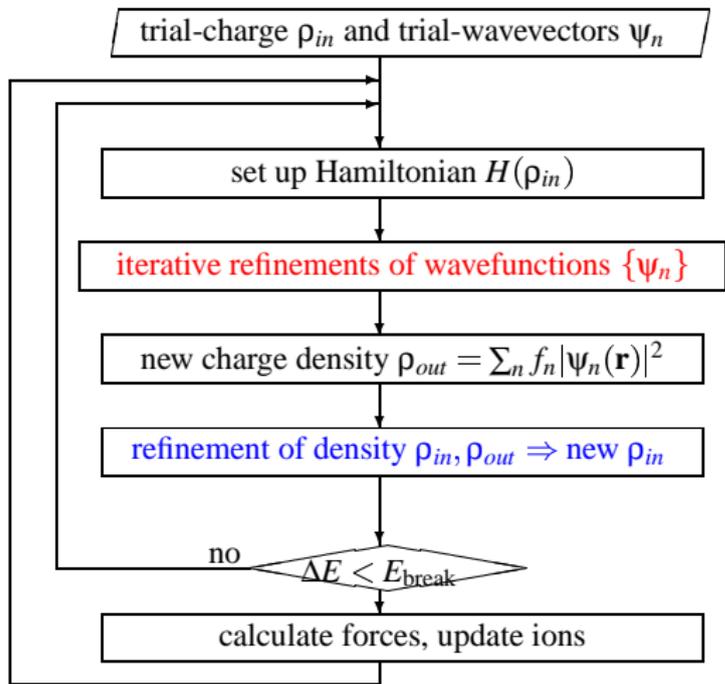
the Free Energy Functional

$$F_{KS}[\phi, f, \vec{R}] = \sum_n f_n \langle \phi_n | \hat{T} | \phi_n \rangle - \sum_n \sigma S(f_n) \\ + E_H[\rho] + E_{xc}[\phi, f] + \int V_{\text{ion}}(\vec{r}) \rho(\vec{r}) d^3\vec{r}$$

- \vec{R} : ions' positions,
- f_n : levels' occupancies,
- ϕ : $1 - e^-$ orbitals
- electron density $\rho = \sum_{n=1}^{\text{occ}} f_n |\psi_n(\vec{r})|^2$
- going beyond DFT,

$$E_{xc}[\phi, f] = \underbrace{E_{xc}^{\text{loc}}[\rho]}_{\text{LDA, GGA}} + \underbrace{E_x^{\text{nl}}[\phi, f]}_{\text{XXC}}$$

the Self-Consistency Cycle



2 optimization loops

- **inner (el)**: refinement of wavefunctions:
 optimization of $\{\psi_n\}$
- **outer (el)**: refinement of ρ_{in} charge density mixing
- **outer (ionic)** refinement of atoms' positions:
 minimisation of the forces

Numerical Determination of the electronic groundstate

Iteration to Self-Consistency

self-consistent solution of $\mathbf{H}\Psi = E\Psi$

- **old-fashioned:**

- 1 start with a trial ρ_{in}^0
- 2 solve the Schrödinger eqn.
- 3 calculate the new density $\rho_{out} = \sum^{occ} |\psi_n|^2$
- 4 mix charge densities: $\rho_{new} = n\rho_{in} + (n-1)\rho_{out}$
- 5 construct the new Schrödinger eqn. using ρ_{new}
- 6 iterate 2-5 until convergence is reached

– slow

Numerical Determination of the electronic groundstate

Direct Minimization of the Functional

- **modern**, based on the method of Car-Parrinello:
- used if the diagonalization of \mathbf{H} is the bottleneck of the calculation
- minimize the value of the **functional** $F_n(\vec{r})$

$$\text{gradient : } F_n(\vec{r}) = \left[-\frac{\hbar^2}{2m_e} \nabla^2 + V^{\text{eff}}(\vec{r}, \rho(\vec{r})) - \epsilon_n \right] \phi_n$$

- start with a set of trial wavefunctions $\phi_n^0(\vec{r})$ with $n = 1, \dots, N_e/2$ (eg random numbers)
- converge each band iteratively, starting from ϕ_n^0 , diagonalizing the Hamiltonian
- supported by VASP (versions up from vasp.4.6)

Basic Algorithms used in VASP

Overview

- almost all algorithms used by VASP are based on **iterative matrix diagonalization** schemes
 - 1 blocked Davidson (DAV)
 - 2 conjugate gradient (CG)
 - 3 residual minimization (RMM), direct inversion in the iterative subspace (DIIS)
- a small amount of a **residual vector** $|R_n\rangle$ is added to the function f to refine f ($f = |\phi_n\rangle, \rho, \dots$)
- in iterative diagonalization methods, $|R(\phi_n)\rangle$ is used to update the wavefunction: $\phi'_n = \phi_n + \lambda R_n$ (in the sense of a steepest descent approach)
- minimize the norm of $|R_n\rangle$

Basic Algorithms used in VASP

Residual Vectors: wavefunction ($|\phi_n\rangle$)

- start with some trial ϕ_n for an eigenstate n of \hat{H}
- variation of the **Rayleigh quotient** with respect to $\langle \phi_n | \rightarrow$ **residual vector** $|R(\phi_n)\rangle$:

$$\epsilon_n^{\text{appr.}} = \frac{\langle \phi_n | \mathbf{H} | \phi_n \rangle}{\langle \phi_n | \mathbf{S} | \phi_n \rangle} \rightarrow |R(\phi_n)\rangle = (\mathbf{H} - \epsilon_n^{\text{appr.}} \mathbf{S}) | \phi_n \rangle$$

- aim: find a matrix **K** which gives the exact error of the wavefunction (**preconditioning**), to find the optimal $|R_n\rangle$

Basic Algorithms used in VASP

Preconditioning (I)

- aim: find a unitary matrix (“rotation matrix”) \mathbf{K} that yields:
- the exact error in the trial wavefunction (ideally in a single step)
- a preconditioned residual vector $|p_n\rangle = \mathbf{K}|R_n\rangle$
- based on the ansatz of Teter *et.al.*:
as E_{kin} dominates \mathbf{H} for large \vec{G} , $\rightarrow \mathbf{K} = \mathbf{K}(\frac{3}{2}E_{kin}(\vec{R}))$
G. Kresse, J. Furthmüller, Phys. Rev. **B 54**, 11169, (1996),

$$\langle \mathbf{G} | \mathbf{K} | \mathbf{G}' \rangle = \delta_{\mathbf{G}\mathbf{G}'} \frac{27 + 18x + 12x^2 + 8x^3}{27 + 18x + 12x^2 + 8x^3 + 16x^4}, \quad \text{with}$$

$$x = \frac{\hbar^2 G^2}{2m \frac{3}{2} E_{kin}(\vec{R})}$$

Basic Algorithms used in VASP

Preconditioning (II)

- preconditioning using hybrid functionals (M. Marsman, G. Kresse, to be published): the optimal \mathbf{K} to optimize

$$\begin{aligned} \bar{F}[\mathbf{K}, f'] &= \sum_n \sum_{kl} f'_n \mathbf{K}_{nl}^* \mathbf{K}_{nk} \langle \phi_l | \hat{T} | \phi_k \rangle - \sum_n \sigma S(f'_n) \\ &+ E_H[\rho] + \bar{E}_{xc}[\mathbf{K}, f'] + \int V_{\text{ion}}(\vec{r}) \rho(\vec{r}) d^3\vec{r} \end{aligned}$$

with $\rho(\vec{r}) = \sum_n \sum_{kl} f'_n \mathbf{K}_{nl}^* \mathbf{K}_{nk} \phi_l^*(\vec{r}) \phi_k(\vec{r})$

- $\phi'_n = \sum_m \mathbf{K}_{nm} \phi_m$
- linearization of E_{xc} around the present set of orbitals:
- matrix elements for a fixed, non-local Fock V_{xc} calculated at the start of the self-consistency procedure, not updated during the search of the optimal \mathbf{K}_{nm} .

Basic Algorithms used in VASP

Blocked Davidson Scheme (DAV)

- 1 select **subset** $\{\phi_k^1 | k = 1, \dots, n_1\}$ of **all bands** $\{\phi_n | n = 1, \dots, N_{\text{bands}}\}$
- 2 optimize ϕ_k^1 by adding the orthogonalized preconditioned $|R_n\rangle$ ($|p_n\rangle$) to the presently considered subspace
- 3 Rayleigh Ritz optimization in the space spanned by these vectors ("sub-space" rotation in the $2 * n_1$ dim. space)
- 4 determine n_1 lowest vectors $\{\phi_k^2 | k = 1, \dots, n_1\}$
- 5 iterate 2-4 if required
- 6 store the optimized w.f. back in the set $\{\phi_k | k = 1, \dots, n_1, \dots, N_{\text{bands}}\}$.
- 7 continue steps 1-4 with next sub-block $\{\phi_k^1 | k = n_1 + 1, \dots, 2n_1\}$
- 8 after each block of band has been optimized:
Rayleigh Ritz optimization in the space $\{\phi_k | k = 1, \dots, N_{\text{bands}}\}$
- 9 approximately a factor of 1.5-2 slower than RMM-DIIS, but always stable.

Basic Algorithms used in VASP

Blocked Davidson (DAV)

- 1 $\{\phi_n | n = 1, \dots, N_{\text{bands}}\} \Rightarrow \{\phi_k^1 | k = 1, \dots, n_1\}$
- 2 optimize this subset

$$\phi_k^1 / g_k^1 = \underbrace{\left(1 - \sum_{n=1}^{N_{\text{bands}}} |\phi_n\rangle \langle \phi_n | \mathbf{S}\right)}_{\text{orthonormalization operator}} \mathbf{K} (\mathbf{H} - \epsilon_{\text{app}} \mathbf{S}) \phi_k^1 \quad | k = 1, \dots, n_1 >$$

- 3 Rayleigh Ritz optimization $\rightarrow \{\phi_k^2 | k = 1, n_1\}$
- 4 add additional preconditioned residuals

$$\phi_k^2 / g_k^1 / g_k^2 = \left(1 - \sum_{n=1}^{N_{\text{bands}}} |\phi_n\rangle \langle \phi_n | \mathbf{S}\right) \mathbf{K} (\mathbf{H} - \epsilon_{\text{app}} \mathbf{S}) \phi_k^2 \quad | k = 1, \dots, n_1$$

- 5 add a fourth set of preconditioned vectors if required,...

Basic Algorithms used in VASP

Conjugate Gradient (CG)

- **strictly sequential**: bands are optimized one after another
- optimization of F_{KS} with respect to the wavefunctions yields a gradient $|g_n\rangle$

$$|g_n\rangle = \underbrace{f_n \left(1 - \sum_m |\phi_m\rangle\langle\phi_m|\right) \hat{H} |\phi_n\rangle}_1 + \underbrace{\sum_m \frac{1}{2} \mathbf{H}_{nm} (f_n - f_m) |\phi_m\rangle}_2$$

with $\hat{H} = \hat{T} + \hat{V}_{\text{ion}} + \hat{V}_H(\rho) + \hat{V}_{\text{xc}}[\phi, f]$

- \hat{V}_{xc} includes the local V_{xc} (and the non-local screened Fock-exchange).
- **1**: changes in F_{KS} with respect of changes in the ϕ orthogonal to the subspace spanned by the current ϕ
- **2**: changes in F_{KS} with the subspace spanned by the current ϕ (=0 if only occupied orbitals are included)

Basic Algorithms used in VASP

Conjugate Gradient (CG)

- search direction determined by using Loewdin's perturbation theory:

$$\mathbf{U}_{nm} = \delta_{nm} - \Delta s \frac{\mathbf{H}_{nm}}{\mathbf{H}_{mm} - \mathbf{H}_{nn}}, \quad \phi'_n = \sum_m \mathbf{U}_{nm} \phi_m$$

$\mathbf{U} \dots$ unitary matrix, chosen such that $\langle \phi'_n | \mathbf{H} | \phi'_m \rangle = \epsilon_m \delta_{nm}$

- step direction $\approx \mathbf{H}_{mm} - \mathbf{H}_{nn}$
- Δs step width along the search direction
- implemented algorithms include:
 - (preconditioned) steepest descent
 - (preconditioned) conjugated gradient

Basic Algorithms used in VASP

Residual Minimization - direct inversion in the iterative subspace (RMM-DIIS)

- most time consuming step in CG: orthonormalization of the preconditioned residual vector to the current set of trial wavefunctions (for each single band update)
- avoided by minimizing the **norm of the residual vector** instead of the Rayleigh Ritz quotient
P. Pulay, Chem. Phys. Lett. **73**,393 (1980), D.M. Wood, A. Zunger, J. Phys **A**, 1343 (1985)).
- each vector is optimized **individually**
- fast
- drawback: always finds the vector which is closest to the initial trial vector: \rightarrow if the initial set does not span the real ground state, some states may be “missing” in the final solution.

Basic Algorithms used in VASP

Residual Minimization - direct inversion in the iterative subspace (RMM-DIIS)

- 1 calculate a preconditioned residual vector $\mathbf{K}|R_m^0\rangle = \mathbf{K}|R(\phi_m^0)\rangle$
- 2 perform a trial step with width λ along this direction:
 $|\phi_m^1\rangle = |\phi_m^0\rangle + \lambda \mathbf{K}|R_m^0\rangle$
- 3 \rightarrow new residual vector $|R_m^1\rangle = |R(\phi_m^1)\rangle$
- 4 search for the linear combination of $|\phi_m^0\rangle$ and $|\phi_m^1\rangle$,
 $|\phi_m^M\rangle = \sum_{i=0}^M \alpha_i |\phi_m^i\rangle$ (here: $M = 1$),
yielding $|R_m^M\rangle = \sum_{i=0}^M \alpha_i |R_m^i\rangle$
minimize $\|R\|$ by determining the lowest eigenvector/eigenvalue of
 $\sum_{j=0}^M \langle R_m^i | R_m^j \rangle \alpha_j = \epsilon \sum_{j=0}^M \langle \phi_m^i | \mathbf{S} | \phi_m^j \rangle \alpha_j$
- 5 start from 1, using $|\phi_m^M\rangle$ and $|R_m^M\rangle$

Basic Algorithms used in VASP

Further Algorithms

- based on CG: simultaneous update of all orbitals
- MD-like Damped velocity friction algorithm (see lecture 3)
(requires the definition of a timestep)
- exact diagonalization: whenever there is a substantial amount
($> 30\text{-}50\%$) of unoccupied bands (eg for *GW* calculations)
- subspace rotation and diagonalization in the sub-space
spanned by NBANDS

Parameters to be set in INCAR

choice of the electronic convergence algorithms

- **ALGO** algorithms to be used (alternative: IALGO):
implemented in vasp.4.6 and vasp.5
Normal (DAV) | Fast (DAV+RMM-DIIS) | VeryFast (RMM-DIIS) |
implemented in vasp.5 only
| Damped (damped MD) | All (damped MD+precond. CG)
| Exact | Diag | Subrot | Eigenval | None | Nothing |
- for Hybrid functionals, always use direct optimization (A, Exact)
- **LDIAG** (True | False): perform subspace diagonalization
- **TIME** time step for damped MD-based algorithms

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Charge Density Mixing

DIIS Mixing Algorithms

- calculation of the input density for the next el. step from $\rho_{new} = m\rho_{in} + (m - 1)\rho_{out}$:
- minimize the norm of the residual vector $R[\rho_{in}] = \rho_{out}[\rho_{in}] - \rho_{in}$
- assume R can be linearized around ρ_{sc} :

$$\begin{aligned}
 R[\rho] &= -\mathbf{J}(\rho - \rho_{sc}) \\
 R[\rho] &\approx R[\rho]^{(m)} - \mathbf{J}^{(m)}(\rho^{(m)} - \rho_{sc}) \\
 \rho^{(m+1)} &= \rho^{(m)} + \mathbf{G}^{(m)}(\rho_{out}^{(m)} - \rho_{in}^{(m)}) \\
 \mathbf{G}^{(m)} &= -\mathbf{J}^{(m)-1}
 \end{aligned}$$

Charge Density Mixing

DIIS Mixing

- $\mathbf{J} = 1 - \chi \mathbf{U}$: “charge dielectric” (Jacobian) matrix:
- in a system with a dielectric susceptibility χ , an external charge perturbation ($\Delta\rho$) leads to a change in the potential $\mathbf{U} = \frac{4\pi e^2}{\mathbf{q}^2}$.
- model dielectric function implemented in VASP:
G.P. Kerker, Phys.Rev.B**23**, 3082 (1981):

$$\mathbf{J} \approx \text{AMIX} \cdot \max\left(\frac{q^2}{q^2 + \text{BMIX}}, \text{AMIN}\right)$$

BMIX ... \mathbf{q} – cutoff wavevector for the Kerker approx.

Charge Density Mixing

DIIS Mixing

- the convergence behaviour is determined by the width of the eigenvalue spectrum of $\mathbf{J} = 1 - \chi \frac{4\pi e^2}{\mathbf{q}^2}$
- **insulators, semiconductors**: constant, independent of the system size $L \Rightarrow$ good convergence
- **metals**:
 - short wavelength limit (large \mathbf{q}) $\rightarrow \mathbf{J} \approx \mathbf{1}$: no screening
 - long wavelength limit: the screening term dominates \mathbf{J} :
 $\rightarrow \mathbf{J} \approx \mathbf{q}^{-2} \sim L^2$
 \Rightarrow the width of the spectrum is proportional to the square of the longest dimension of the lattice
 \Rightarrow poor convergence, possibly charge sloshing.

Charge Density Mixing

Available Mixing Algorithms

- **Linear** Mixing ($n = \text{AMIX}$)

$$\rho_{in}^{(m+1)} = n\rho_{in}^{(m)} + (n-1)\rho_{out}^{(m)}$$
- **Kerker** Mixing (BMIX)

$$\rho_{mix}(G) = \rho_{in}(G) + \text{AMIX} \cdot \max\left(\frac{G^2}{G^2 + \text{BMIX}}, \text{AMIN}\right) [\rho_{out}(G) - \rho_{in}(G)]$$

- **Broyden** Mixing, ($\text{WC} = 0$)
 D.D.Johnson, Phys.Rev.B**38**, 12807 (1988)
 information of the current iteration (m) updates \mathbf{J}^{-1} but also overrides information of from previous iterations
- **Pulay** Mixing ($\text{WC} > 0$)
 P.Pulay, Chem.Phys.Lett**73**, 393 (1980)
 information from all previous iterations is included with equal weights.

Charge Density Mixing

Available Mixing Algorithms

- **Tchebycheff** mixing via a 2nd order equation of motion, using a simple velocity Verlet algorithm
H.Akai and P.H.Dederichs, J.Phys.C **18**, 2455 (1985)

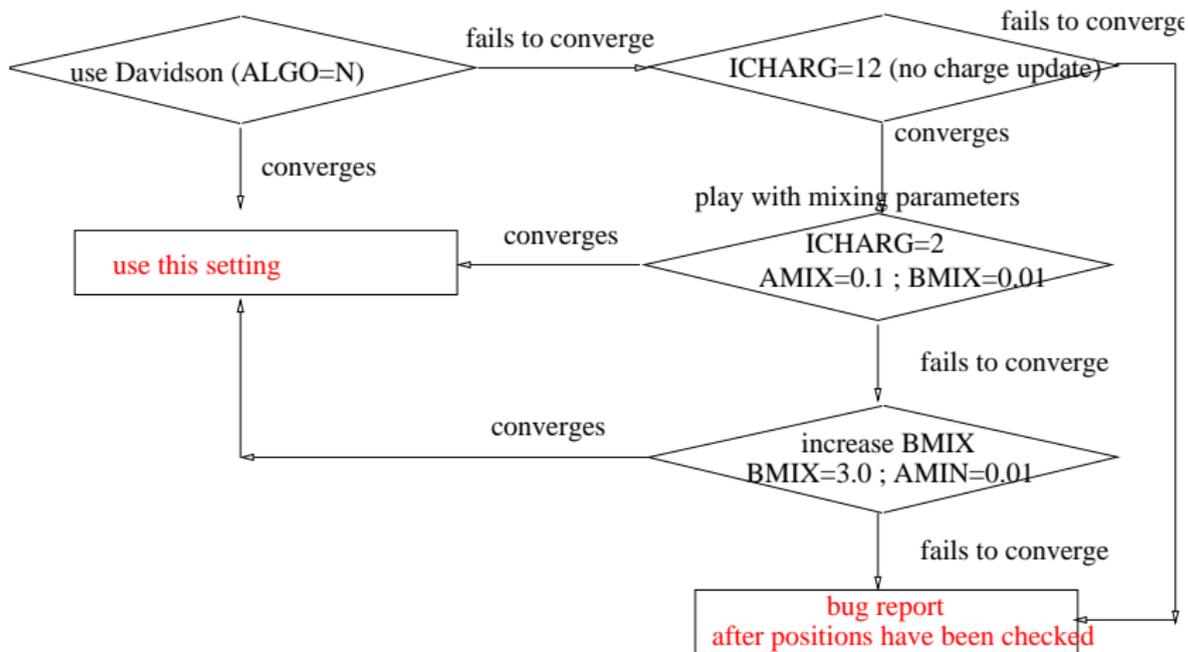
$$\begin{aligned}\ddot{\rho}_{mix}(\mathbf{G}) &= 2 \cdot \mathbf{J}(\mathbf{G})[\rho_{out}(\mathbf{G}) - \rho_{in}(\mathbf{G})] - \mu \dot{\rho}_{in}(\mathbf{G}) \\ \mu &= \text{friction (damping) factor}\end{aligned}$$

Charge Density Mixing

Parameters to be set in INCAR

- **IMIX**: Mixing type:
0 (no mixing) | 1 (Kerker) | 2 (Tchebycheff) |
4 Broyden ($WC=0$) or Pulay ($WC>0$)
- Kerker mixing **BMIX**, **BMIX_MAG**: cutoff wavevectors
- for Broyden-type mixing: **INIMIX**, **MIXPE**, **MAXMIX**, **WC**
 - INIMIX functional form of the initial mixing matrix
 - MIXPRE metric for the Broyden scheme
 - MAXMIX max. # of steps stored in the Broyden scheme
 - WC weight factor for each iteration

what to do if convergence fails (DFT-level)



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Some Basics

Periodicity

- perfect periodic lattices: translational symmetry: each unit cell is repeated at \vec{R} by shifting it by $N \cdot \vec{a}$ ($\vec{a} = n_1 \vec{a}_1 + n_2 \vec{a}_2 + n_3 \vec{a}_3$ lattice vector) with respect to some “origin of the lattice”:
- applying a **translation operator** $\hat{T}_{\vec{a}_i}$: $\hat{T}_{\vec{a}_i}(\vec{0}) = \vec{R}$
- \hat{T} and \hat{H} commute ($[\hat{T}, \hat{H}] = 0$)
 $\Rightarrow \hat{T}$ and \hat{H} have the same eigenfunctions.

$$\hat{T}_{\vec{R}} |\vec{0}\rangle = |\vec{R}\rangle = \lambda \cdot |\vec{0}\rangle$$

$$\langle \vec{R} | \vec{R} \rangle = \lambda^* \lambda \cdot \langle \vec{0} | \vec{0} \rangle$$

$$\Rightarrow \lambda^* \lambda = 1$$

$$\Rightarrow \lambda = e^{i\vec{k} \cdot \vec{R}}, \quad k \in \mathbf{R}$$

Some Basics (continued)

periodicity (continued)

- translation by a lattice vector \vec{R}

$$\hat{T}_{\vec{R}} |\vec{0}\rangle = |\vec{R}\rangle = e^{i\vec{k}\cdot\vec{R}} \cdot |\vec{0}\rangle$$

- \Rightarrow for any Ψ that satisfies the Schrödinger equation in a periodic potential, $\exists \vec{k}$ such, that a translation by \vec{R} is equivalent to a multiplication by the phase factor $e^{i\vec{k}\cdot\vec{R}}$, eg. for e^- -waves

$$\Psi(\vec{r} + \vec{R}) = e^{i\vec{k}\cdot\vec{R}} \Psi(\vec{r}).$$

periodicity: Range of \vec{k}

- for any lattice vector of the reciprocal lattice defined by unit vectors ($\vec{b}_i = \frac{2\pi}{\Omega} \vec{a}_j \times \vec{a}_k$)
 $\vec{G}_n = m_1 \vec{b}_1 + m_2 \vec{b}_2 + m_3 \vec{b}_3$,
- let $\vec{k}' = \vec{k} + \vec{G}_n$,

$$\Psi_{\vec{k}'}(\vec{r} + \vec{R}) = e^{i \cdot \vec{k}' \cdot \vec{R}} \Psi(\vec{r}) = e^{i \cdot \vec{k} \cdot \vec{R}} \underbrace{e^{i \cdot \vec{G}_n \cdot \vec{R}}}_{\equiv 1} \Psi(\vec{r})$$

- range of allowed values for \vec{k} : within the first Brillouin zone (BZ)

$$0 < k \leq \frac{2\pi}{a} \text{ or } -\frac{\pi}{a} < k \leq \frac{\pi}{a}$$

- for finite crystals: $\# \vec{k} \neq \infty$
 $\rightarrow ?$ allowed number of $\vec{k} \rightarrow$ **quantization of \vec{k}**

Some Basics (continued)

Quantisation of \vec{k}

- cyclic **Born-von Kármán boundary conditions** ($l = N_1 a_1$)
- unperturbed (ideal) crystal (eg 1D chain with length l),
- N_1 : number of unit cells of the macroscopic crystal along x
- N_1 : large enough to provide that effects of the crystal shape are negligible.

$$\begin{aligned} \Psi(\vec{x} + N_1 \vec{a}_1) &= \Psi(\vec{x}), & \vec{\nabla} \Psi(\vec{x} + N_1 \vec{a}_1) &= \vec{\nabla} \Psi(\vec{x}) \\ \Psi(x + N_1 a_1) &= e^{ik_1 N_1 a_1} \Psi(x) \Rightarrow e^{ik_1 N_1 a_1} = 1 \\ k_1 N_1 a_1 &= 2\pi m_1 \Rightarrow k_1 = \frac{2\pi m_1}{N_1 a_1}, \quad m_1 \in Z \\ 0 < m_1 &\leq N_1 \quad \text{or} \quad -\frac{N_1}{2} < m_1 \leq \frac{N_1}{2} \end{aligned}$$

Some Basics (continued)

energy bands

- proper wavefunctions in a periodic lattice: $\Psi_{\vec{k}}(\vec{r}) = \underbrace{e^{i\vec{k}\vec{r}}}_{\text{BlochFactor}} \cdot u(\vec{r})$

where $u(\vec{r})$ is a cell-periodic function of the lattice

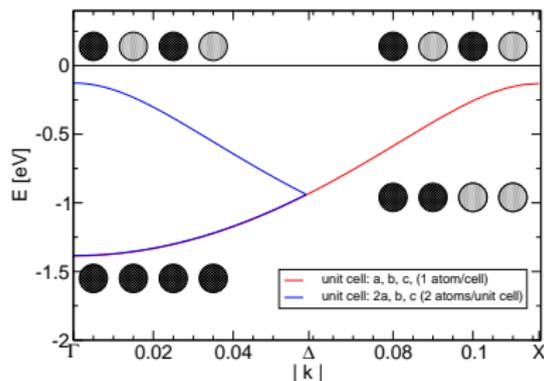
- the eigenvalues $\epsilon_n(\vec{k})$ of a crystal of *fixed, finite* volume V : *discrete* spectrum of \hat{H} :

$$\hat{H}\Psi_{\vec{k}+\vec{G}_n}(\vec{r}) = \hat{H}\Psi_{n\vec{k}}(\vec{r}) = \epsilon_{\vec{k}+\vec{G}_n}\Psi_{n\vec{k}}(\vec{r}), \quad \epsilon_{\vec{k}+\vec{G}_n} = \epsilon_n(\vec{k})$$

- $\forall n$: the set of electronic levels $\epsilon_n(\vec{k})$ is the " n^{th} **energy band**".
- the eigenstates and -values are periodic with \vec{k} in the reciprocal lattice ("extended zone scheme")

Some Basics (continued)

s-like bands for a primitive cell and a supercell with 2 atoms



Supercells

- example: bandstructure of (super)cells containing 1 (2) atoms with 2 s -electrons
- $\vec{a}' = 2\vec{a} \Rightarrow \vec{k}'_1 = \frac{1}{2}\vec{k}_1$
- folding of the bandstructure

cell size	$1a$	$2a$
# bands	1	2
\vec{k} -pts	Γ	Γ
	Δ	X
	X	Γ

- \Rightarrow for constant \vec{k} -grid-density:

$$N(\vec{k}') = \frac{1}{2}N(\vec{k})$$

Sampling of the Brillouin Zone

Integrals over the Brillouin zone I_{BZ} :

- for the calculation of e.g. Density of states (DOS), Charge densities,
- **Integrals** over the Brillouin zone are usually replaced by **sums** over special \vec{k} -points:

-

$$I(\epsilon) = \frac{1}{\Omega_{BZ}} \int_{BZ} F(\epsilon) \delta(\epsilon_{n\vec{k}} - \epsilon) d\vec{k} \longrightarrow \sum_{\vec{k}} w_{\vec{k}_i} F(\epsilon) \delta(\epsilon_{n\vec{k}} - \epsilon)$$

- **Symmetry** of the lattice: BZ \longrightarrow irreducible BZ (IBZ)

$$\Omega_{IBZ} = \frac{\Omega_{BZ}}{N_{\hat{R}}}$$

- $N_{\hat{R}}$: number of symmetry operations of the point group

Sampling of the Brillouin Zone

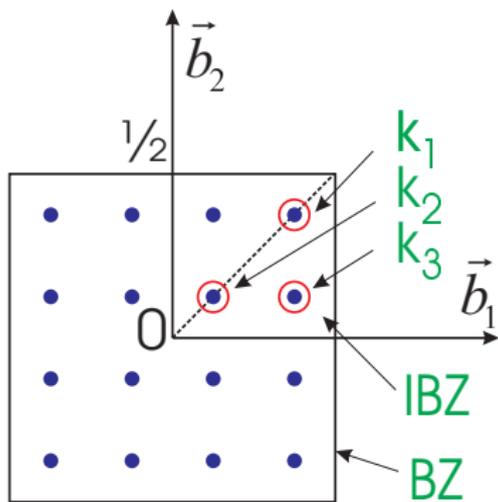
\vec{k} -mesh generation

- the BZ should be covered by equally-spaced \vec{k} -point grids, e.g. Monkhorst-Pack meshes
 H.J. Monkhorst, J.D. Pack, PRB **13**, 5188, (1976)

$$\vec{k} = \vec{b}_1 \frac{n_1 + s_1}{N_1} + \vec{b}_2 \frac{n_2 + s_2}{N_2} + \vec{b}_3 \frac{n_3 + s_3}{N_3}$$

- \vec{b} unit vector of the BZ
- s_i optional shift along direction i
- N_i number of subdivisions along i

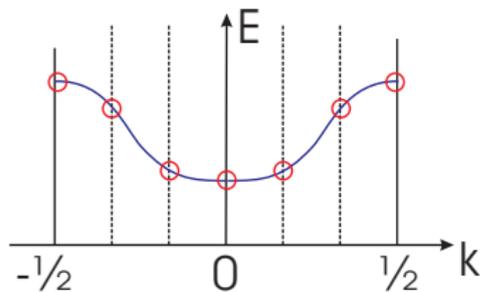
example of a MP-mesh of a 2D square lattice



Mesh data

- full BZ: $N_1 = N_2 = 4 \Rightarrow n_{\vec{k}}(\text{BZ})=16$
- $N_{\hat{R}} = 4 \Rightarrow n_{\vec{k}}(\text{IBZ}) = 4$
- $w_{\vec{k}_1} = w_{\vec{k}_2}(\text{IBZ}) = \frac{4}{16} = \frac{1}{4}$
- $w_{\vec{k}_3} = \frac{8}{16} = \frac{1}{2}$
- $\frac{1}{\Omega_{\text{BZ}}} \int_{\text{BZ}} F(\vec{k}) d\vec{k} \rightarrow \frac{1}{4}F(\vec{k}_1) + \frac{1}{4}F(\vec{k}_2) + \frac{1}{2}F(\vec{k}_3)$

example: bandstructure energy



e.g: one s -like band

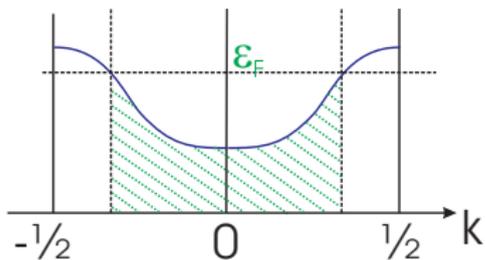
- $F(\vec{k}) = \epsilon(\vec{k})$
- $E = \sum_k w_{k_i} \epsilon_{k_i}$
- Γ : no nodes in $\Psi \Rightarrow \epsilon = \min$
- X : max # of nodes in $\Psi \Rightarrow \epsilon = \max$
- to increase the accuracy:
- increase the density of the \vec{k} -mesh

Smearing Methods

problem in **metallic systems**: some bands cross the Fermi level

$$E_F = \mu$$

⇒ discontinuity of the **occupancy** f of bands at $E_F = \mu$



band n crossing E_f

- eg: bandstructure energy

$$E_b = \sum_{n, \vec{k}_i} w_{\vec{k}_i} \epsilon(\vec{k}_i, n) f(\epsilon(\vec{k}_i, n) - \mu)$$

- occupancy of state (\vec{k}_i, n)

$$f(\epsilon(\vec{k}_i, n) - \mu) = \begin{cases} 1 & \dots & \epsilon(\vec{k}_i, n) \leq \mu \\ 0 & \dots & \epsilon(\vec{k}_i, n) > \mu \end{cases}$$

Smearing Methods

Fermi-Dirac smearing



$$f\left(\frac{\epsilon_{(n,\vec{k})} - \mu}{\sigma}\right) = \frac{1}{\exp\left(\frac{\epsilon_{(n,\vec{k})} - \mu}{\sigma}\right) + 1}$$

- $\sigma = k_B T$... smearing parameter (\approx electronic T of the system)
- energy E is no longer variational with respect to the partial occupancies f
- the new variational functional is the **Free energy F**

$$F = E - \sum_n \sigma S(f_n)$$
- **S : entropy** of a system of non-interacting electrons at a finite temperature T
- $S(f) = - [f \ln f + (1 - f) \ln(1 - f)]$

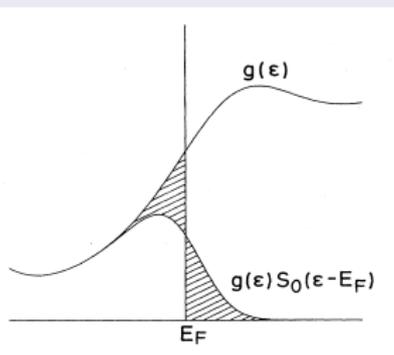
Smearing Methods

Gaussian Smearing

- levels are broadened with a Gaussian function
- f is the integral of the Gaussian function:
- $f\left(\frac{\epsilon_{n,\vec{k}} - \mu}{\sigma}\right) = \frac{1}{\sqrt{2\pi\sigma^2}} \exp\left(-\frac{\left(\frac{\epsilon_{n,\vec{k}} - \mu}{\sigma}\right)^2}{2}\right)$, $\int f = \frac{1}{2} \left[1 - \operatorname{erf}\left(\frac{\epsilon_{n,\vec{k}} - \mu}{\sigma}\right)\right]$
- analytical inversion of the error-function erf does not exist
- $\Rightarrow S$ and F cannot be written in terms of f ,
- $S\left(\frac{\epsilon - \mu}{\sigma}\right) = \frac{1}{2\sqrt{\pi}} \exp\left(-\frac{\left(\frac{\epsilon - \mu}{\sigma}\right)^2}{2}\right)$
- σ has no physical interpretation.
- variational functional $F(\sigma)$ differs from $E(0)$.
- **Forces:** $\vec{F}(F(\sigma))$ are not necessarily equal to $\vec{F}(E(0))$.
- workaround: extrapolation to $\sigma \rightarrow 0$:

Smearing Methods

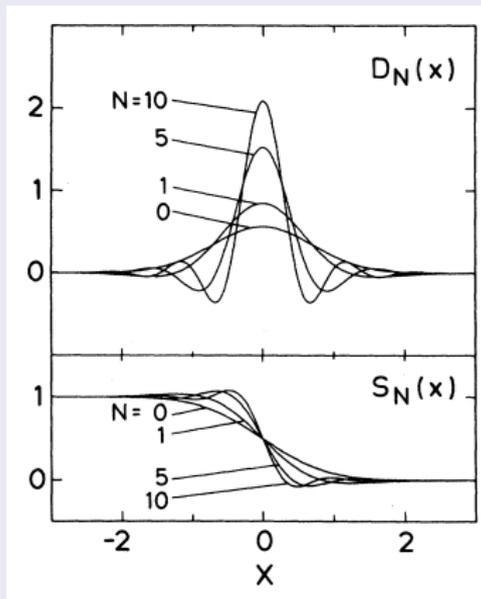
Methfessel-Paxton smearing



- generalization of Gaussian broadening with functions of higher order
- expansion of stepfunction in a complete set of orthogonal functions:
 - Hermite polynomials of order N
 - term of $N = 0$: integral over Gaussians

Smearing Methods

Methfessel-Paxton smearing



MP smearing

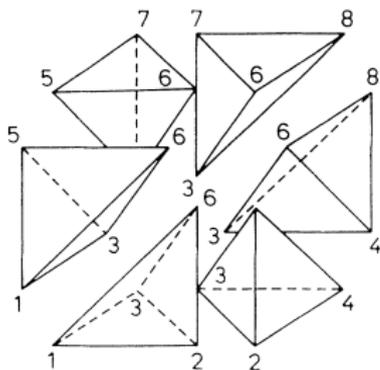
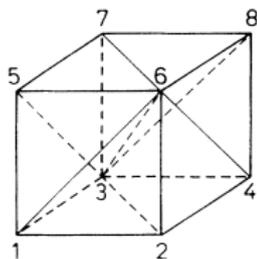
- Hermite-polynomial of order N
 $f_0(x) = \frac{1}{2} (1 - \text{erf}(x))$
 $f_N(x) =$
 $f_0(x) + \sum_{m=1}^N A_m H_{2m-1}(x) e^{-x^2}$
 $S_N(x) = \frac{1}{2} A_N H_{2N}(x) e^{-x^2}$
- deviation of $F(\sigma)$ from $E(0)$ only of order $2+N$ in σ
- extrapolation for $\sigma \rightarrow 0$ usually not necessary, but possible:
- $E(0) \approx \hat{E}(\sigma) =$
 $\frac{1}{N+2} ((N+1)F(\sigma) + E(\sigma))$

Smearing Methods

Methfessel-Paxton Smearing

- MP of order N leads to a negligible error, if $F(\epsilon)$ is representable as a polynomial of degree $2N$ around ϵ_F .
- linewidth σ can be increased for higher order N to obtain the same accuracy
- "entropy term": $S = \sigma \sum_n S_N(f_n)$ describes deviation of $F(\sigma)$ from $E(\sigma)$.
 - \Rightarrow if $S < \text{few meV}$: $\hat{E}(\sigma) \approx F(\sigma) \approx E(\sigma) \approx E(0)$.
 - \Rightarrow forces correct within that limit.
- in practice: smearings of order $N=1$ or 2 are sufficient

Tetrahedron Integration



The Linear Tetrahedron Method

- (I)BZ is subdivided into tetrahedra spanned by the \vec{k} -points
- function X to be integrated: linearly interpolated between the tetrahedra $\rightarrow \bar{X}$

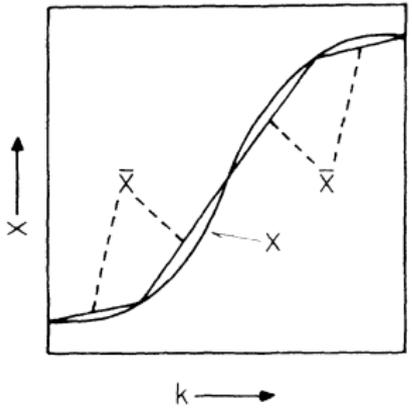
- tetrahedra are remapped onto the \vec{k} -points, \vec{k} -points have **effective weights** (\approx occupancies)

$$w_{nj} = \frac{1}{\Omega_{\text{BZ}}} \int_{\Omega_{\text{BZ}}} d\vec{k} c_j(\vec{k}) f(\epsilon_n(\vec{k}))$$

- $\bar{X} = \sum_{j=1}^4 c_j(\vec{k}) X(\vec{k}_j) \leftarrow \int \bar{X}$

Tetrahedron Integration

Possible Drawbacks of the Linear T.M.



- $\geq 4\vec{k}$ -pts necessary, Γ must be included
- tetrahedra can break the symmetry of the Bravais lattice
- linear interpolation of f may under- or overestimate the real curve
- the errors due to this linear interpolation only cancel for full bands (problem for metals)
- the afforded density of the \vec{k} -mesh (# of tetrahedra) can be large

T.M., Blöchl Corrections

improvements, drawbacks

P.Blöchl *et.al.*, PRB**49**, 16223 (1994)

- for metals: correction of quadratic errors is possible

$$\delta w_{\vec{k}n} = \sum_{\text{T}} \frac{1}{40} D_{\text{T}}(E_F) \sum_{j=1}^4 (\epsilon_{jn} - \epsilon_{\vec{k}n})$$

($T \dots$ tetrahedra, $D \dots$ DOS of T at $E = E_F$)

- best \vec{k} -point convergence for energy
- drawbacks (if used for metals):
 - w_{nj} : not variational with the change of ionic positions
 - \Rightarrow the new effective partial occupancies do not minimize the groundstate total energy
 - \Rightarrow variation of occupancies $w_{n\vec{k}}$ w.r.t. the ionic positions would be necessary
 - with US-PP and PAW practically impossible

\vec{k} -point generation

choice of \vec{k} -points as implemented in VASP

- used files: KPOINTS, INCAR
- generate **equally spaced \vec{k} - mesh**
- **shift** it by s_i (if shift is defined in KPOINTS)
- apply the **symmetry operations** of the symmetry group of the lattice if ISYM > 0: this includes the symmetries of the
 - Bravais lattice (POSCAR) ,
 - atomic positions (POSCAR) ,
 - pre-set MD-velocities (POSCAR) ,
 - magnetic ordering (INCAR)
- extract the **\vec{k} points lying in the IBZ** (\rightarrow IBZKPT)
- calculate the proper **weights $w_{\vec{k}_i}$**

Input files: KPOINTS

specifies the \vec{k} mesh to be used

Automatic mesh

0

G (M)

4 4 4

0. 0. 0.

general format for scf runs, DOS

- 1 header (comment)
- 2 $N_{\vec{k}} = 0$: automatic generation scheme
- 3 Γ (M)-centered MP grid
- 4 # of subdivisions N_i along b_i
- 5 optional shift of the mesh (s_i)

Input files: KPOINTS

```

high symm.  lines
10
Line-mode
rec
0 0 0
0.5 0.0 0

0.5 0.0 0
0.5 0.5 0.0

0.5 0.5 0.0
0.5 0.5 0.5
  
```

for bandstructure plots (DFT only)

eg for a simple cubic structure

- ① header (comment)
- ② intersections along each given symmetry line in the BZ
- ③ $\Gamma-X$
- ④ $X-M$
- ⑤ $M-R$

this format must not be used for hybrid functional band structures

Input files: INCAR

BZ-integration related Input Parameters

- **ISMEAR=**: BZ integration method :
-1 (Fermi) | 0 (Gaussian) | 1,2 MP | -5 (Blöchl)
for relaxation of metals use 1 or 2
- **SIGMA**: smearing width σ :
S-contribution to F should not exceed a few meV/atom
small-gap semiconductors!: $\sigma < \frac{1}{2} E_{gap}$
- **ISYM**: use of symmetrisation (\vec{k} -mesh spans the BZ or the IBZ)
-1 | 0 (no symm) | 1,2 (symmetry used)

Setup of a proper \vec{k} -mesh

Some Hints

- always check for proper **\vec{k} -mesh convergence** before the production runs
- **supercells**: rescale the \vec{k} -mesh (preserve the density of the mesh)
- **slabs** (long axis \perp to the surface, eg z) : $N_1 \times N_2 \times 1$
- **free atoms, molecules** $1 \times 1 \times 1$ (Γ -point only)
- \vec{k} meshes for tetrahedra BZ-integration have to include Γ and the \vec{k} - points at the BZ-edges
- the KPOINTS - file format for DFT band-structure plots **must not** be used for calculations using hybrid functionals.